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Inclosure Material:
Metal
Overall Length:
0.210 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.230 inches
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-71
Electrode Internally-electrically Connected To Case:
Collector
Component Name And Quantity:
2 transistor
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
45.0 collector to base voltage, dc all transistor and 45.0 collector to emitter voltage, dc all transistor and 7.0 emitter to base voltage, dc
transistor
Current Rating Per Characteristic:
50.00 milliamperes source cutoff current all transistor
Power Rating Per Characteristic:
400.0 milliwatts small-signal input power, common-collector preset all transistor
Transfer Ratio:
80.0 static forward current transfer ratio, common-emitter all transistor
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Special Features:
All transistor junction pattern arrangement: npn
Terminal Type And Quantity:
8 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Ves - demil/mli

Yes - demil/mli

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